WHAT IS CLAIMED IS:

1. A method of chemical mechanical polishing comprising the steps of:

supplying a slurry; and

polishing an object with particles contained in the slurry, wherein the polishing step including a step of controlling a physical quantity, which is a determinant factor of a polishing speed with respect to the object, based on information on the particles contained in the slurry.

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- 2. The method of chemical mechanical polishing according to claim 1, wherein a target polishing speed is set according to the type or quality of the surface film of the object to be polished, and the physical quantity is controlled such that the target polishing speed becomes constant.
- 3. A method of chemical mechanical polishing comprising the steps of:

supplying a slurry; and

polishing an object with particles contained in the slurry, wherein the polishing step including a step of controlling a polishing time based on information on the particles contained in the slurry.

4. An apparatus for chemical mechanical polishing comprising:

a first slurry supplying unit which supplies a first slurry;

a second slurry supplying unit which supplies a second slurry;

a polishing unit which receives the first slurry from said first slurry supplying unit and the second slurry from said second slurry supplying unit and polishes an object with particles contained in the slurry; and

a control unit which controls supply of slurry from said first slurry supplying unit and said second slurry supplying unit to said polishing unit according to a polishing speed with respect to the object to be polished.

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5. An apparatus for chemical mechanical polishing comprising:

a first slurry supplying unit which supplies a first slurry;

20 a second slurry supplying unit which supplies a second
slurry;

a polishing unit which receives the first slurry from said first slurry supplying unit and the second slurry from said second slurry supplying unit and polishes an object with particles contained in the slurry; and

a control unit which controls supply of slurry from said first slurry supplying unit and said second slurry supplying unit to said polishing unit according to the type or quality of the surface film of the object.

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- 6. An apparatus for chemical mechanical polishing comprising:
 - a slurry supplying unit;

a polishing unit which receives the slurry from said slurry supplying unit and polishes an object with particles contained in the slurry;

a polishing particle information acquiring unit which acquires information on the particles contained in the slurry to be supplied to said polishing unit; and

a polishing and driving controlling unit which controls a physical quantity, which is a determinant factor of a polishing speed with respect to the object, based on the information on the particles acquired by said polishing particle information acquiring unit.

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- 7. The apparatus according to claim 6, wherein said slurry supplying unit includes a first slurry supplying unit which supplies a first slurry; and a second slurry supplying unit which supplies a second slurry, and
- said apparatus further comprising a mixture slurry

supplying unit which receives and mixes the first slurry supplied by said first slurry supplying unit with the second slurry supplied by said second slurry supplying unit and supplies the mixed slurry to said polishing unit.

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8. The apparatus according to claim 7, further comprising:

a mixture ratio controlling unit which controls a ratio of the quantities of the first slurry and the second slurry when mixing them based on the information on the particles acquired by said polishing particle information acquiring unit.

- 9. An apparatus for chemical mechanical polishing
 15 comprising:
 - a slurry supplying unit;
 - a polishing unit which receives the slurry from said slurry supplying unit and polishes an object with particles contained in the slurry;
- a polishing particle information acquiring unit which acquires information on the particles contained in the slurry to be supplied to said polishing unit; and
 - a polishing and driving controlling unit which controls a polishing time based on the information on the particles acquired by said polishing particle information

acquiring unit.

10. The apparatus according to claim 9, wherein said slurry supplying unit includes a first slurry supplying unit which supplies a first slurry; and a second slurry supplying unit which supplies a second slurry, and

said apparatus further comprising a mixture slurry supplying unit which receives and mixes the first slurry supplied by said first slurry supplying unit with the second slurry supplied by said second slurry supplying unit and supplies the mixed slurry to said polishing unit.

11. The apparatus according to claim 10, further comprising:

a mixture ratio controlling unit which controls a ratio of the quantities of the first slurry and the second slurry when mixing them based on the information on the particles acquired by said polishing particle information acquiring unit.

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12. An apparatus for chemical mechanical polishing comprising:

a first slurry supplying unit which supplies a first slurry;

a second slurry supplying unit which supplies a second

slurry;

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a mixture slurry supplying unit which receives and mixes the first slurry supplied by said first slurry supplying unit with the second slurry supplied by said second slurry supplying unit;

a polishing unit which receives the mixture of slurries from said mixture slurry supplying unit and polishes an object with particles contained mixture of slurries;

a polishing speed detecting unit which detects a polishing speed with respect to the object; and

a mixture ratio controlling unit which controls said first slurry supplying unit and said second slurry supplying unit so as to control a ratio of the quantities of the first slurry and the second slurry, when supplying them to said mixture slurry supplying unit for mixing, based on the polishing speed detected by said polishing speed detecting unit.

13. An apparatus for chemical mechanical polishing20 comprising:

a first slurry supplying unit which supplies a first
slurry;

a second slurry supplying unit which supplies a second slurry;

a mixture slurry supplying unit which receives and

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mixes the first slurry supplied by said first slurry supplying unit with the second slurry supplied by said second slurry supplying unit;

a polishing unit which receives the mixture of slurries from said mixture slurry supplying unit and polishes an object with particles contained mixture of slurries;

a polishing particle information acquiring unit which acquires information on the particles contained in the mixture slurry to be supplied to said polishing unit; and

a mixture ratio controlling unit which controls said first slurry supplying unit and said second slurry supplying unit so as to control a ratio of the quantities of the first slurry and the second slurry, when supplying them to said mixture slurry supplying unit for mixing, based on the information on the particles acquired by said polishing particle information acquiring unit.